

# 2SK2379

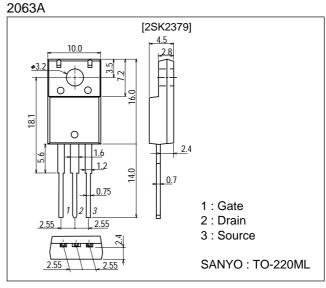
## **Ultrahigh-Speed Switching Applications**

### Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- Low-voltage drive.
- Micalless package facilitaing mounting.

## **Package Dimensions**

unit : mm



## **Specifications**

### Absolute Maximum Ratings at Ta= $25^{\circ}C$

| Parameter                   | Symbol | Conditions             | Ratings     | Unit |
|-----------------------------|--------|------------------------|-------------|------|
| Drain-to-Source Voltage     | VDSS   |                        | 200         | V    |
| Gate-to-Source Voltage      | VGSS   |                        | ±20         | V    |
| Drain Current (DC)          | ۱D     |                        | 20          | А    |
| Drain Current (Pulse)       | IDP    | PW≤10µs, duty cycle≤1% | 80          | А    |
| Allowable Power Dissipation | D-     |                        | 2.0         | W    |
|                             | PD     | Tc=25°C                | 40          | W    |
| Channel Temperature         | Tch    |                        | 150         | °C   |
| Storage Temperature         | Tstg   |                        | -55 to +150 | °C   |

#### Electrical Characteristics at Ta=25°C

| Parameter                         | Symbol   | Conditions                                 | Ratings |     |     | Unit |
|-----------------------------------|----------|--|---------|-----|-----|------|
|                                   |          |  | min     | typ | max | Unit |
| Drain-to-Source Breakdown Voltage | V(BR)DSS | ID=1mA, VGS=0                              | 200     |     |     | V    |
| Gate-to-Source Breakdown Voltage  | V(BR)GSS | I <sub>G</sub> =±100μA, V <sub>DS</sub> =0 | ±20     |     |     | V    |
| Zero-Gate Voltage Drain Current   | IDSS     | V <sub>DS</sub> =200V, V <sub>GS</sub> =0  |         |     | 100 | μA   |
| Gate-to-Source Leakage Current    | IGSS     | V <sub>GS</sub> =±16V, V <sub>DS</sub> =0  |         |     | ±10 | μΑ   |
| Cutoff Voltage                    | VGS(off) | V <sub>DS</sub> =10V, I <sub>D</sub> =1mA  | 1.5     |     | 2.5 | V    |
| Forward Transfer Admittance       | yfs      | V <sub>DS</sub> =10V, I <sub>D</sub> =10A  | 9.5     | 16  |     | S    |

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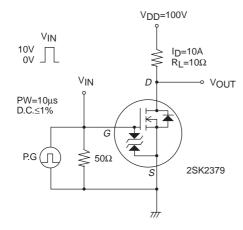
## 查询"2SK2379"供应商

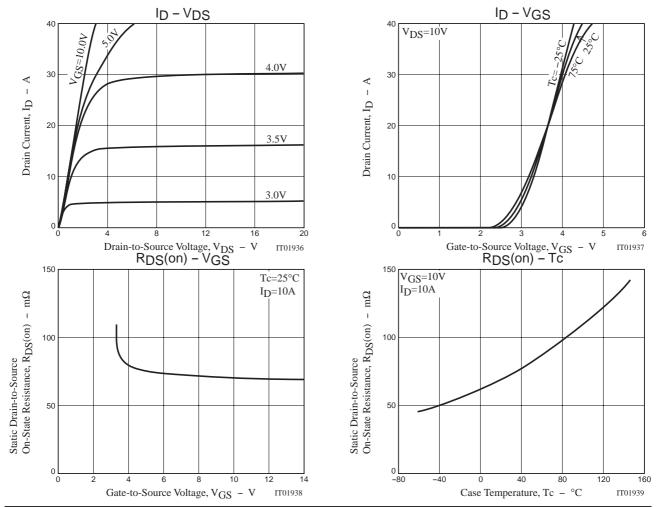
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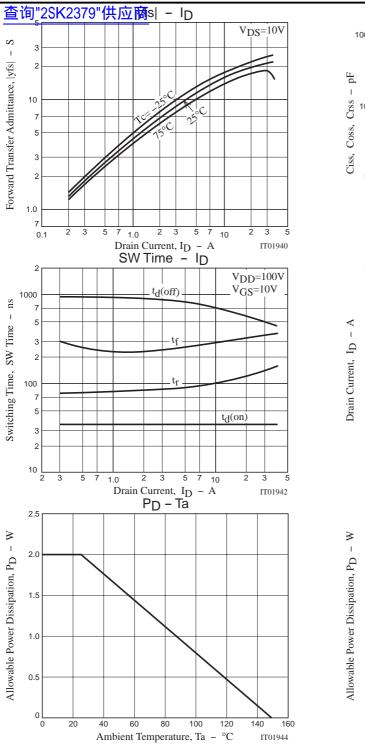
| Parameter                                  | Symbol               | Conditions                                |     | Ratings |     |      |
|--|----------------------|---|-----|---------|-----|------|
|  |                      |   | min | typ     | max | Unit |
| Static Drain-to-Source On-State Resistance | R <sub>DS</sub> (on) | I <sub>D</sub> =10A, V <sub>GS</sub> =10V |     | 70      | 95  | mΩ   |
| Input Capacitance                          | Ciss                 | VDS=20V, f=1MHz                           |     | 2400    |     | pF   |
| Output Capacitance                         | Coss                 | V <sub>DS</sub> =20V, f=1MHz              |     | 500     |     | pF   |
| Reverse Transfer Capacitance               | Crss                 | V <sub>DS</sub> =20V, f=1MHz              |     | 200     |     | pF   |
| Turn-ON Delay Time                         | t <sub>d</sub> (on)  | See specified Test Circuit                |     | 35      |     | ns   |
| Rise Time                                  | tr                   | See specified Test Circuit                |     | 100     |     | ns   |
| Turn-OFF Delay Time                        | t <sub>d</sub> (off) | See specified Test Circuit                |     | 710     |     | ns   |
| Fall Time                                  | tf                   | See specified Test Circuit                |     | 290     |     | ns   |
| Diode Forward Voltage                      | VSD                  | IS=20A, VGS=0                             |     | 1.0     | 1.5 | V    |

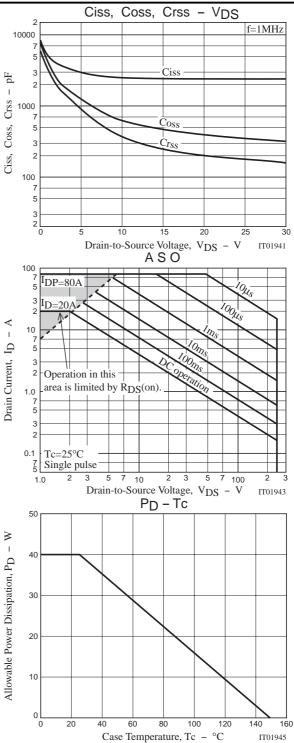
Marking : K2379

#### Switching Time Test Circuit









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